

## MM74HCT00

### Quad 2 Input NAND Gate

#### General Description

The MM74HCT00 is a NAND gates fabricated using advanced silicon-gate CMOS technology which provides the inherent benefits of CMOS—low quiescent power and wide power supply range. This device is input and output characteristic and pin-out compatible with standard 74LS logic families. All inputs are protected from static discharge damage by internal diodes to  $V_{CC}$  and ground.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices.

These parts are also plug-in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

#### Features

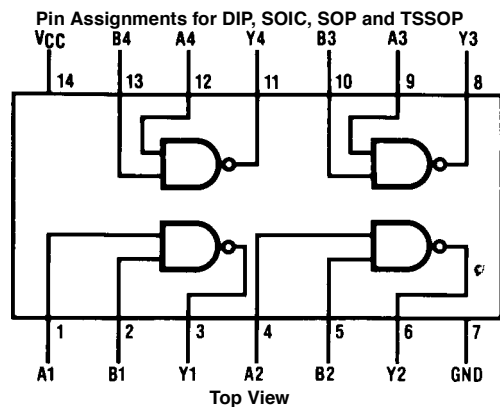
- TTL, LS pin-out and threshold compatible
- Fast switching:  $t_{PLH}$ ,  $t_{PHL}$  = 14 ns (typ)
- Low power: 10  $\mu$ W at DC
- High fan out, 10 LS-TTL loads

#### Ordering Code:

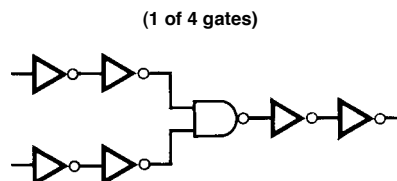
Order Number	Package Number	Package Description
MM74HCT00M	M14A	14-Lead Small Outline Integrate Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
MM74HCT00SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCT00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCT00N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

#### Connection Diagram



#### Logic Diagram



**Absolute Maximum Ratings**(Note 1)

(Note 2)

Supply Voltage ( $V_{CC}$ )	-0.5 to +7.0V
DC Input Voltage ( $V_{IN}$ )	-1.5 to $V_{CC}+1.5V$
DC Output Voltage ( $V_{OUT}$ )	-0.5 to $V_{CC}+0.5V$
Clamp Diode Current ( $I_{IK}, I_{OK}$ )	$\pm 20$ mA
DC Output Current, per pin ( $I_{OUT}$ )	$\pm 25$ mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	$\pm 50$ mA
Storage Temperature Range ( $T_{STG}$ )	-65°C to +150°C
Power Dissipation ( $P_D$ )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature ( $T_L$ )	
(Soldering 10 seconds)	260°C

**Recommended Operating Conditions**

	Min	Max	Units
Supply Voltage ( $V_{CC}$ )	4.5	5.5	V
DC Input or Output Voltage ( $V_{IN}, V_{OUT}$ )	0	$V_{CC}$	V
Operating Temperature Range ( $T_A$ )	-40	+85	°C
Input Rise or Fall Times ( $t_r, t_f$ )		500	ns

**Note 1:** Absolute Maximum Ratings are those values beyond which damage to the device may occur.**Note 2:** Unless otherwise specified all voltages are referenced to ground.**Note 3:** Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C.**DC Electrical Characteristics** $V_{CC} = 5V \pm 10\%$  (unless otherwise specified)

Symbol	Parameter	Conditions	T <sub>A</sub> = 25°C		T <sub>A</sub> = -40 to 85°C	T <sub>A</sub> = -55 to 125°C	Units
			Typ	Guaranteed Limits			
V <sub>IH</sub>	Minimum HIGH Level Input Voltage			2.0	2.0	2.0	V
V <sub>IL</sub>	Maximum LOW Level Input Voltage			0.8	0.8	0.8	V
V <sub>OH</sub>	Minimum HIGH Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		I <sub>OUT</sub>   = 20 μA	V <sub>CC</sub>	V <sub>CC</sub> -0.1	V <sub>CC</sub> -0.1	V <sub>CC</sub> -0.1	V
		I <sub>OUT</sub>   = 4.0 mA, V <sub>CC</sub> = 4.5V	4.2	3.98	3.84	3.7	V
		I <sub>OUT</sub>   = 4.8 mA, V <sub>CC</sub> = 5.5V	5.2	4.98	4.84	4.7	V
V <sub>OL</sub>	Maximum LOW Level Voltage	V <sub>IN</sub> = V <sub>IH</sub>					
		I <sub>OUT</sub>   = 20 μA	0	0.1	0.1	0.1	V
		I <sub>OUT</sub>   = 4.0 mA, V <sub>CC</sub> = 4.5V	0.2	0.26	0.33	0.4	V
		I <sub>OUT</sub>   = 4.8 mA, V <sub>CC</sub> = 5.5V	0.2	0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> = V <sub>CC</sub> or GND, V <sub>IH</sub> or V <sub>IL</sub>		±0.05	±0.5	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>OUT</sub> = 0 μA		1.0	10	40	μA
		V <sub>IN</sub> = 2.4V or 0.5V (Note 4)	0.18	0.3	0.4	0.5	mA

**Note 4:** This is measured per input with all other inputs held at  $V_{CC}$  or ground.

**AC Electrical Characteristics**
 $V_{CC} = 5.0V$ ,  $t_r = t_f = 6\text{ ns}$ ,  $C_L = 15\text{ pF}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

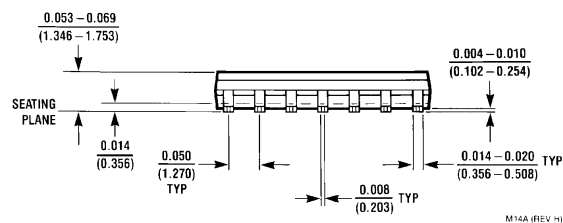
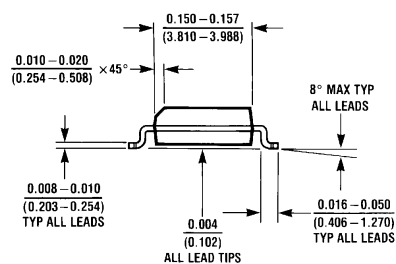
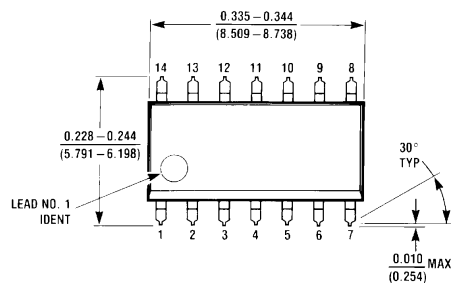
Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
$t_{PLH}$ , $t_{PHL}$	Maximum Propagation Delay		14	18	ns

**AC Electrical Characteristics**
 $V_{CC} = 5.0V \pm 10\%$ ,  $t_r = t_f = 6\text{ ns}$ ,  $C_L = 50\text{ pF}$  (unless otherwise noted)

Symbol	Parameter	Conditions	$T_A = 25^\circ\text{C}$		$T_A = -40\text{ to }85^\circ\text{C}$	$T_A = -55\text{ to }125^\circ\text{C}$	Units
			Typ	Guaranteed Limits			
$t_{PLH}$ , $t_{PHL}$	Maximum Propagation Delay		18	23	29	35	ns
$t_{THL}$ , $t_{TLH}$	Maximum Output Rise & Fall Time		8	15	19	22	ns
$C_{PD}$	Power Dissipation Capacitance	(Note 5)	30				pF
$C_{IN}$	Input Capacitance		5	10	10	10	pF

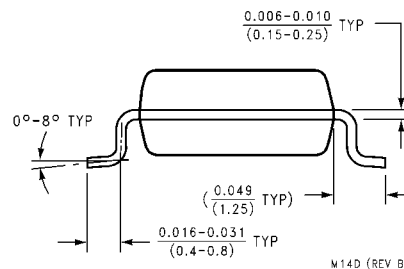
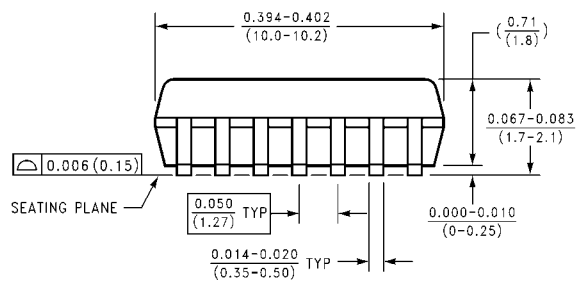
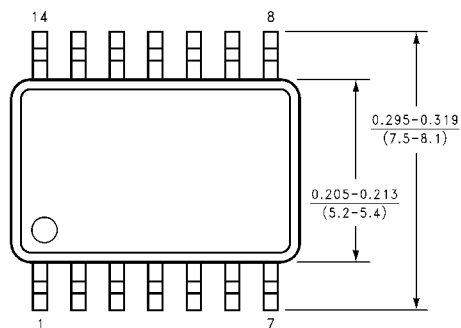
**Note 5:**  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .

# Physical Dimensions inches (millimeters) unless otherwise noted



M14A (REV H)

**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow  
Package Number M14A**

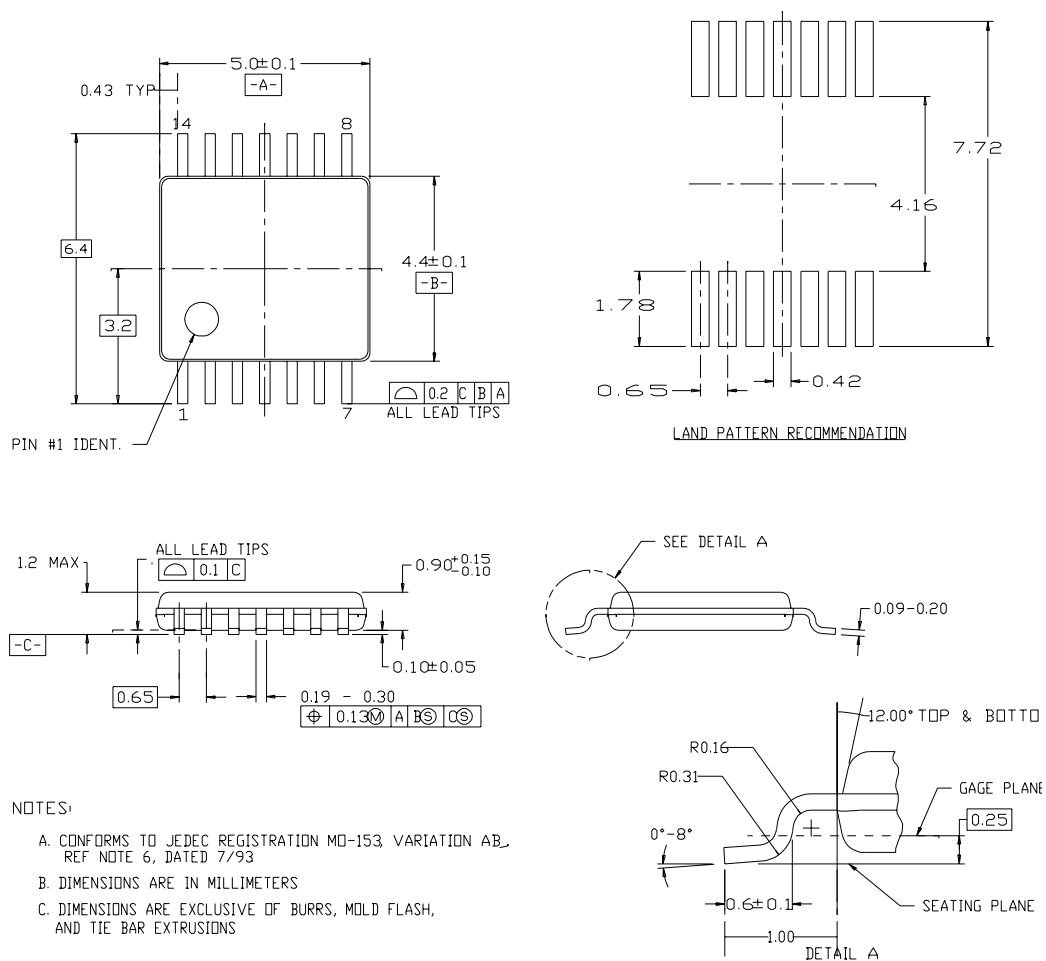


M14D (REV B)

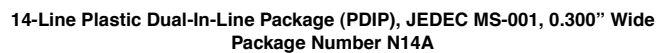
**14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide  
Package Number M14D**

# Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

14LD, TSSOP, JEDEC MO-153, 4.4MM WIDE



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide  
Package Number MTC14



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